# **UTC** UNISONIC TECHNOLOGIES CO.,LTD

### MGBR15L40

Preliminary

DIODE

## MOS GATED BARRIER RECTIFIER

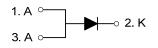
#### DESCRIPTION

The UTC **MGBR15L40** is a surface mount mos gatedbarrier rectifier, it uses UTC's advanced technology to provide customers withlow forward voltage drop and high switching speed, etc.

#### FEATURES

\* Low forward voltage drop \* High switching speed

#### SYMBOL



#### ORDERING INFORMATION

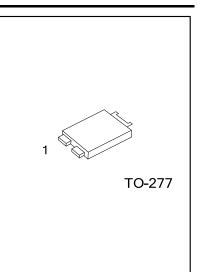
Ordering Number		Deskars	Pin Assignment			Desking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MGBR15L40L-T27-R	MGBR15L40G-T27-R	TO-277	А	К	А	Tape Reel	

#### Note: Pin Assignment: A: Anode K: Common Cathode

MGBR15L40L-T27-R (1)Packing Type (2)Package Type (3)Lead Free	<ul> <li>(1) R: Tape Reel</li> <li>(2) T27: TO-227</li> <li>(3) L: Lead Free, G: Halogen Free</li> </ul>	1
(3)Lead Free	(3) L: Lead Free, G: Halogen Free	

#### MARKING INFORMATION

PACKAGE	MARKING
TO-277	UTC MGBR15L40 C: Lead Free G: Halogen Free Lot Code



#### ■ ABSOLUTE MAXIMUM RATINGS(T<sub>A</sub>=25°C, unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.						
PARAMETER		SYMBOL	RATINGS	UNIT		
DC Blocking Voltage		V <sub>RM</sub>	40	V		
WorkingPeak Reverse Voltage		V <sub>RWM</sub>	40	V		
Peak Repetitive Reverse Voltage		V <sub>RRM</sub>	40	V		
Average Rectified Output Current	T <sub>C</sub> =140°C	lo	15	А		
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load		I <sub>FSM</sub>	180	A		
Repetitive Peak Avalanche Power (1µs, 25°C)		P <sub>ARM</sub>	5000	W		
Operating Junction Temperature		TJ	-65~+150	°C		
Storage Temperature		T <sub>STG</sub>	-65~+150	°C		

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### ■ THERMAL CHARACTERISTICS (Note 3)

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	θ <sub>JA</sub>	73	°C/W	
Junction to Case	θις	13	°C/W	

#### ■ ELECTRICAL CHARACTERISTICS(T<sub>A</sub>=25°C, unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	V <sub>(BR)R</sub>	I <sub>R</sub> =0.5mA	40			V
Forward Voltage Drop		I <sub>F</sub> =15A, TJ=25°C			0.58	V
		I <sub>F</sub> =15A, T <sub>J</sub> =125°C			0.53	V
Lockers Current (Note 1)	DM	V <sub>R</sub> =40V, T <sub>J</sub> =25°C		80	300	μA
Leakage Current (Note 1)		V <sub>R</sub> =40V, T <sub>J</sub> =125°C		12	40	mA

Notes: 1. Short duration pulse test used to minimize self-heating effect.

2. Thermal resistance junction to case mounted on heatsink.

3. Mounted on an FR4 PCB, single-sided copper, with 100cm<sup>2</sup> copper pad area.



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